



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/814,074	03/30/2004	Clinton F. Walker	42P18956	5486

8791 7590 09/20/2006

BLAKELY SOKOLOFF TAYLOR & ZAFMAN
12400 WILSHIRE BOULEVARD
SEVENTH FLOOR
LOS ANGELES, CA 90025-1030

EXAMINER

SPITTLE, MATTHEW D

ART UNIT	PAPER NUMBER
----------	--------------

2111

DATE MAILED: 09/20/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 10/814,074	Applicant(s) WALKER ET AL.	
	Examiner Matthew D. Spittle	Art Unit 2111	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 30 June 2006.
- 2a) ☐ This action is FINAL. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-20 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-20 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Claims 1 – 20 have been examined.

Claim Rejections - 35 USC § 102

5 The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

10 (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 – 4, 6 and 7 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Yoo et al. (U.S. 6,834,014).

15 Regarding claim 1, Yoo et al. describe a memory device, comprising:

An address bus interface (column 4, lines 27 – 29; Figure 4, items 410a, 410b);

An address bus termination circuit that can be enabled or disabled (Figure 4, items enclosed by boxes 420, 440; column 5, line 57 – column 6, line 13);

20 An address bus termination control signal input (Figure 2; where the input is interpreted as the input to the switches SW3, SW4, SW5, SW6 connected to items CON1, CON2) wherein the address bus terminal control signal input is operable to enable the address bus termination circuit when the address bus termination control signal input is tied to a first voltage level, and wherein the address bus termination control signal input is operable to disable the address bus termination circuit when the
25 address bus termination control signal input is tied to a second voltage level (column 7,

Art Unit: 2111

lines 40 – 44 describe where the control signal CON being at a first voltage level (low level) and the termination resistor being OFF; column 8, lines 5 – 10 describe where the control signal CON is at a second voltage level (high level) and the termination resistor is turned ON).

30

Regarding claim 2, Yoo et al. describe the address bus termination circuit to be enabled if an asserted address bus termination control signal (Figure 2, items CON1, CON2) is received at the address bus termination control signal input (column 7, lines 40 – 44 describe where the control signal CON being at a first voltage level (low level) and the termination resistor being OFF; column 8, lines 5 – 10 describe where the control signal CON is at a second voltage level (high level) and the termination resistor is turned ON).

35

Regarding claim 3, Yoo et al. describe the address bus termination circuit to be disabled if the address bus termination circuit control signal (Figure 2, items CON1, CON2) is not asserted (column 7, lines 40 – 44 describe where the control signal CON being at a first voltage level (low level) and the termination resistor being OFF; column 8, lines 5 – 10 describe where the control signal CON is at a second voltage level (high level) and the termination resistor is turned ON).

40

45

Regarding claim 4, Yoo et al. describe wherein the address bus termination control signal (Figure 2, items CON1, CON2) is asserted when at a logically high

Art Unit: 2111

voltage level and is not asserted when at a logically low voltage level (column 7, lines 40 – 44 describe where the control signal CON being at a first voltage level (low level) and the termination resistor being OFF; column 8, lines 5 – 10 describe where the control signal CON is at a second voltage level (high level) and the termination resistor is turned ON).

Regarding claim 6, Yoo et al. describe a data bus interface (column 4, lines 27 – 29; Figure 4, items 410a, 410b) and a data bus termination circuit (column 4, lines 27 – 33; column 5, lines 11 – 13).

Regarding claim 7, Yoo et al. describe a data bus termination control signal input, the data bus termination circuit to be enabled in response to an asserted data bus termination control signal (Figure 4, items enclosed by boxes 420, 440; column 5, line 57 – column 6, line 13; Examiner notes that Yoo et al. describe that their invention can be applied to either address busses or data busses; column 4, lines 27 – 33).

* * *

65

Claim 1 – 3 and 5 – 7 are rejected under 35 U.S.C. 102(b) as being anticipated by Lewis et al. (U.S. 5,313,595).

Regarding claim 1, Lewis et al. describe a memory module, comprising:

A memory device (Figure 1, item 14) comprising:

Art Unit: 2111

70 An address bus interface (Figure 1, items 24, 26, 28, 36);

 An address bus termination circuit that can be enabled or disabled (Figure 3b, item 100; where the enabling is done through the ENABLE/DSCNT pin (104));

 An address bus termination control signal input (Figure 3b, item 104), wherein the address bus termination control signal input is operable to enable the address bus
75 termination circuit when the address bus termination control signal input is tied to a first voltage level (interpreted as a logic low level), and wherein the address bus termination control signal input is operable to disable the address bus termination circuit when the address bus termination control signal input is tied to a second voltage level (interpreted as a logic high level; column 6, lines 30 – 34, 41 – 46).

80

 Regarding claim 2, Lewis et al. describe the address bus termination circuit is enabled if an asserted address bus termination control signal is received at the address bus termination control signal input (where asserting may be interpreted as a logic low level; column 6, lines 30 – 34).

85

 Regarding claim 3, Lewis et al. describe the address bus termination circuit is disabled if the address bus termination control signal is not asserted (where being not asserted may be interpreted as a logic high signal; column 6, lines 41 – 46).

Art Unit: 2111

90 Regarding claim 5, Lewis et al. describe the address bus termination control signal is asserted when at a logically low voltage level and is not asserted when at a logically high voltage level (column 6, lines 30 – 34, 41 – 46).

 Regarding claim 6, Lewis et al. describe wherein each of the plurality of memory
95 devices further includes a data bus interface and a data bus termination circuit (column 4, lines 57 – 64).

 Regarding claim 7, Lewis et al. describe a data bus termination control signal input (Figure 3b, item 104), the data bus termination circuit to be enabled in response to
100 an asserted data bus termination control signal (column 6, lines 30 – 34, 41 – 46).

* * *

 Claims 8 – 10 and 13 – 18 are rejected under 35 U.S.C. 102(b) as being
105 anticipated by Lewis et al. (U.S. 5,313,595).

 Regarding claim 8, Lewis et al. describe a memory module, comprising:

 A plurality of memory devices (interpreted as storage devices; Figure 1, items 22, 34) coupled to an address bus (interpreted as a SCSI bus, column 3, lines 10 – 20, which contains address signals, interpreted as SCSI ID's; column 4, lines 57 – 64) in a
110 daisy chain configuration (Figure 1; column 1, lines 8 – 12), each of the plurality of memory devices including:

Art Unit: 2111

An address bus interface (Figure 1, items 24, 26, 28, 36);

An address bus termination circuit that can be enabled or disabled (Figure 3b, item 100; where the enabling is done through the ENABLE/DSCNT pin (104));

115 An address bus termination control signal input (Figure 3b, item 104), wherein the address bus termination control signal input is operable to enable the address bus termination circuit when the address bus termination control signal input is tied to a first voltage level (interpreted as a logic low level), and wherein the address bus termination control signal input is operable to disable the address bus termination circuit when the
120 address bus termination control signal input is tied to a second voltage level (interpreted as a logic high level; column 6, lines 30 – 34, 41 – 46).

Regarding claim 9, Lewis et al. describe wherein for each of the plurality of memory devices the address bus termination circuit is enabled if an asserted address
125 bus termination control signal is received at the address bus termination control signal input (where asserting may be interpreted as a logic low level; column 6, lines 30 – 34).

Regarding claim 10, Lewis et al. describe wherein for each of the plurality of memory devices the address bus termination circuit is disabled if the address bus
130 termination control signal is not asserted (where being not asserted may be interpreted as a logic high signal; column 6, lines 41 – 46).

Regarding claim 13, Lewis et al. describe wherein for each of the plurality of memory devices the address bus termination control signal is asserted when at a logically low voltage level and is not asserted when at a logically high voltage level (column 6, lines 30 – 34, 41 – 46).

Regarding claim 14, Lewis et al. describe wherein all but the last memory device in the daisy chain configuration has its address bus termination control signal input tied to a positive voltage and the last memory device in the daisy chain configuration has its address bus termination control signal tied to ground (where a positive voltage may be interpreted as a logic high level, and a ground may be interpreted as a logic low level; column 1, lines 32 – 43; column 6, lines 30 – 34, 41 – 46, 47 – 60).

Regarding claim 15, Lewis et al. describe wherein each of the plurality of memory devices further includes a data bus interface and a data bus termination circuit (column 4, lines 57 – 64).

Regarding claim 16, Lewis et al. describe wherein each of the plurality of memory devices further includes a data bus termination control signal input (Figure 3b, item 104), the data bus termination circuit to be enabled in response to an asserted data bus termination control signal (column 6, lines 30 – 34, 41 – 46).

Regarding claim 17, Lewis et al. describe a method comprising:

155 Connecting in a daisy chain configuration ((Figure 1; column 1, lines 8 – 12) an
address bus (interpreted as a SCSI bus, column 3, lines 10 – 20, which contains
address signals, interpreted as SCSI ID's; column 4, lines 57 – 64) to a plurality of
memory devices ((interpreted as storage devices; Figure 1, items 22, 34) on a memory
module (where a module is interpreted as a collection of electronic memory devices;
160 column 3, lines 48 – 50);

Providing address bus termination circuitry in the plurality of memory devices
(Figure 3b, item 100; column 5, lines 46 – 50);

Enabling the address bus termination circuitry of only one of the plurality of
memory devices (column 1, lines 32 – 43; column 6, lines 47 – 60; Examiner notes that
165 that the automatic termination circuitry is directed only to the peripheral devices in the
storage system (i.e., 14, and not the host adapter (18), which has its own termination
circuitry. Therefore, only a single automatic termination circuitry is enabled at any time).

Regarding claim 18, Lewis et al. describe wherein enabling the address bus
170 termination circuitry of only one of the plurality of memory devices includes enabling the
address bus termination circuitry of the last memory device in the daisy chain
configuration (column 1, lines 32 – 43; column 6, lines 47 – 60).

Claim Rejections - 35 USC § 103

175 The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all
obviousness rejections set forth in this Office action:

180 (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

 The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148
USPQ 459 (1966), that are applied for establishing a background for determining
185 obviousness under 35 U.S.C. 103(a) are summarized as follows:

1. Determining the scope and contents of the prior art.
 2. Ascertaining the differences between the prior art and the claims at issue.
 3. Resolving the level of ordinary skill in the pertinent art.
 4. Considering objective evidence present in the application indicating
- 190 obviousness or nonobviousness.

 Claim 4 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lewis et al. (U.S. 5,313,595) in view of Janzen et al. (U.S. 6,538,951).

 Regarding claim 4, Lewis et al. teach the address bus termination control signal
195 is asserted when at a logically low voltage level and is not asserted when at a logically high voltage level (column 6, lines 30 – 34, 41 – 46), but fail to describe wherein the control signal is asserted when at a logically high voltage level and is not asserted when at a logically low voltage level.

 Janzen et al. teach that it is well known in the art to reverse logic states (column
200 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Lewis et al. to reverse logic states as taught by Janzen et al., and designate the control signal as being asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

* * *

Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yoo et al. (U.S. 6,834,014). in view of Janzen et al. (U.S. 6,538,951).

Regarding claim 5, Yoo et al. fail to teach wherein the address bus termination control signal is asserted when at a logically low voltage level and is not asserted when at a logically high voltage level.

Janzen et al. teach that it is well known in the art to reverse logic states (column 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Yoo et al. to reverse logic states as taught by Janzen et al., and designate the control signal as being asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

* * *

225

Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lewis et al. (U.S. 5,313,595) in view of Janzen et al. (U.S. 6,538,951).

Regarding claim 11, Lewis et al. teach wherein for each of the plurality of memory devices the address bus termination control signal is asserted when at a
230 logically low voltage level and is not asserted when at a logically high voltage level (column 6, lines 30 – 34, 41 – 46), but fail to describe wherein the control signal is asserted when at a logically high voltage level and is not asserted when at a logically low voltage level.

Janzen et al. teach that it is well known in the art to reverse logic states (column
235 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Lewis et al. to reverse logic states as taught by Janzen et al., and designate the control signal as being
240 asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

* * *

245 Claim 12 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lewis et al. (U.S. 5,313,595) in view of Janzen et al. (U.S. 6,538,951).

 Regarding claim 12, Lewis et al. teach wherein all but the last memory device in the daisy chain configuration has its address bus termination control signal input tied to a positive voltage and the last memory device in the daisy chain configuration has its
250 address bus termination control signal tied to ground (where ground may be interpreted as a logic low level and a positive voltage may be interpreted as a logic high level; column 6, lines 30 – 34, 41 – 46), but fail to teach the last memory device having its control signal input tied to a positive voltage, while the rest have their control signal input tied to ground.

255 Janzen et al. teach that it is well known in the art to reverse logic states (column 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

 Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Lewis et al. to reverse
260 logic states as taught by Janzen et al., and designate the control signal as being asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

* * *

265

Claim 19 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lewis et al. (U.S. 5,313,595) in view of Janzen et al. (U.S. 6,538,951).

Regarding claim 19, Lewis et al. teach wherein enabling the last memory device in the daisy chain configuration includes coupling an address bus termination control pin
270 to ground (where ground may be interpreted as a logic low level; column 6, lines 30 – 34), but fail to teach the control pin coupled to a positive voltage.

Janzen et al. teach that it is well known in the art to reverse logic states (column 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

275 Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Lewis et al. to reverse logic states as taught by Janzen et al., and designate the control signal as being asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

280

* * *

Claim 20 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lewis et al. (U.S. 5,313,595) in view of Janzen et al. (U.S. 6,538,951).

285 Regarding claim 20, Lewis et al. teach wherein enabling the address bus termination circuitry of only one of the plurality of memory devices includes disabling the address bus termination circuits in all but the last memory device in the daisy chain

Art Unit: 2111

configuration by coupling address bus termination control pins on all but the last memory device to a positive voltage (interpreted as a logic high level; column 6, lines 41 – 60), but fail to teach wherein all but the last memory device in the daisy chain configuration has their address bus termination control signal inputs coupled to ground.

Janzen et al. teach that it is well known in the art to reverse logic states (column 2, lines 25 – 33) since one permutation may permit a simpler, yet functionally equivalent design.

Therefore, it would have been obvious to one of ordinary skill in this art at the time of invention by applicant to modify the memory device of Lewis et al. to reverse logic states as taught by Janzen et al., and designate the control signal as being asserted when at a logically low level instead of a logic high level. This would have been obvious in order to permit a simpler, yet functionally equivalent design.

Response to Arguments

Applicant's arguments, filed June 30th, 2006, with respect to the rejection(s) of claim(s) 8 – 20 under 35 USC 102 and 103 have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of Lewis et al. (U.S. 5,313,595).

In response to Applicant's argument that the active termination signal generators of Yoo are not tied to voltage levels, Examiner notes that Figure 5 and column 6, line 14 – column 7, line 26 discloses the implementation details of the active termination signal

Art Unit: 2111

310 generator. In the illustration, digital logic gates are shown which are operated using high and low logic signals based on high and low voltages. For example, 5 volts = a logic high, and 0 volts = a logic low in a 5-volt logic system as is commonly known in the logic arts. Therefore, since voltage levels operate the activation terminal signal generator, the control inputs are tied to voltage levels.


315

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Any inquiry concerning this communication or earlier communications from the
320 examiner should be directed to Matthew D. Spittle whose telephone number is (571) 272-2467. The examiner can normally be reached on Monday - Friday, 8 - 4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark Rinehart can be reached on 571-272-3632. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.


MARK H. RINEHART
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2100

325 Information regarding the status of an application may be obtained from the
Patent Application Information Retrieval (PAIR) system. Status information for
published applications may be obtained from either Private PAIR or Public PAIR.
Status information for unpublished applications is available through Private PAIR only.
For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should
330 you have questions on access to the Private PAIR system, contact the Electronic
Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a
USPTO Customer Service Representative or access to the automated information
system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

335 
MDS


MARK H. RINEHART
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2100